

4V Drive Nch MOS FET

2SK2504

●Structure

Silicon N-channel MOS FET

●Features

- 1) Low On-resistance.
- 2) Fast switching speed.
- 3) Wide SOA (safe operating area).
- 4) 4V drive.
- 5) Drive circuits can be simple.
- 6) Parallel use is easy.

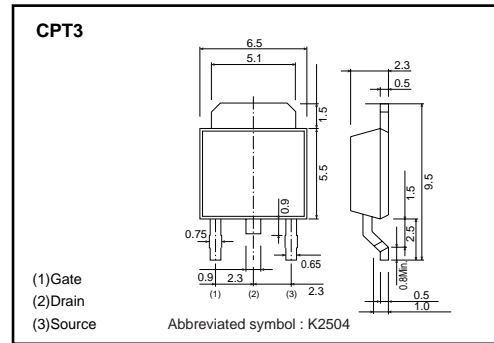
●Applications

Switching

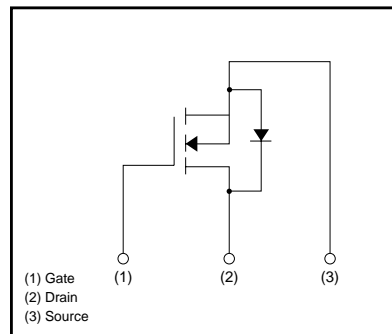
●Packaging specifications

| Type | Package | Taping |
|---------|------------------------------|--------|
| | Code | TL |
| | Basic ordering unit (pieces) | 2500 |
| 2SK2504 | | ○ |

●External dimensions (Unit : mm)



●Inner circuit



●Absolute maximum ratings (Ta=25°C)

| Parameter | Symbol | Limits | Unit | |
|--|------------------|--------------------|------|---|
| Drain-source voltage | V _{DSS} | 100 | V | |
| Gate-source voltage | V _{GSS} | ±20 | V | |
| Drain current | Continuous | I _D | 5 | A |
| | Pulsed | I _{DP} * | 20 | A |
| Reverse drain current | Continuous | I _{DR} | 5 | A |
| | Pulsed | I _{DRP} * | 20 | A |
| Total power dissipation (T _C =25°C) | P _D | 20 | W | |
| Channel temperature | T _{ch} | 150 | °C | |
| Storage temperature | T _{stg} | -55 to +150 | °C | |

* P_w ≤ 10μs, Duty cycle ≤ 1%

Transistors

●Electrical characteristics (Ta=25°C)

| Parameter | Symbol | Min. | Typ. | Max. | Unit | Test Conditions |
|---|----------------------|------|------|------|------|---|
| Gate-source leakage | I _{GSS} | – | – | ±100 | nA | V _{GS} = ±20V, V _{DS} =0V |
| Drain-source breakdown voltage | V _{(BR)DSS} | 100 | – | – | V | I _D =1mA, V _{GS} =0V |
| Zero gate voltage drain current | I _{DSS} | – | – | 10 | μA | V _{DS} =100V, V _{GS} =0V |
| Gate threshold voltage | V _{GS(th)} | 1.0 | – | 2.5 | V | V _{DS} =10V, I _D =1mA |
| Static drain-source on-state resistance | R _{DS(on)} | – | 0.18 | 0.22 | Ω | I _D =2.5A, V _{GS} =10V |
| | | – | 0.25 | 0.28 | | I _D =2.5A, V _{GS} =4V |
| Forward transfer admittance | Y _{fs} * | 4.0 | – | – | S | I _D =2.5A, V _{DS} =10V |
| Input capacitance | C _{iss} | – | 520 | – | pF | V _{DS} =10V |
| Output capacitance | C _{oss} | – | 175 | – | pF | V _{GS} =0V |
| Reverse transfer capacitance | C _{rss} | – | 60 | – | pF | f=1MHz |
| Turn-on delay time | t _{d(on)} | – | 5.0 | – | ns | I _D =2.5A, V _{DD} ≈50V |
| Rise time | t _r | – | 20 | – | ns | V _{GS} =10V |
| Turn-off delay time | t _{d(off)} | – | 50 | – | ns | R _L =20Ω |
| Fall time | t _f | – | 20 | – | ns | R _C =10Ω |

* P_w ≤ 300μs, Duty cycle ≤ 1%

Transistors

●Electrical characteristics curve

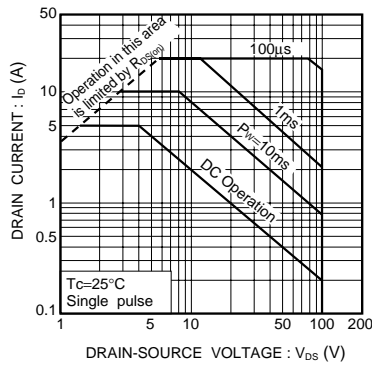


Fig.1 Maximum Safe Operating Area

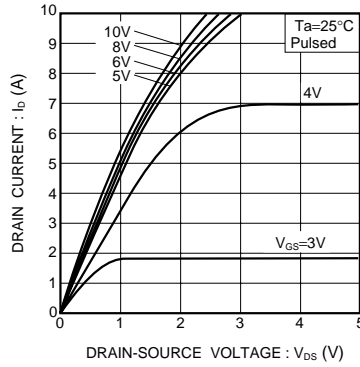


Fig.2 Typical Output Characteristics

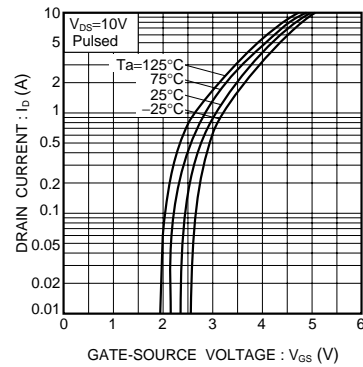


Fig.3 Typical Transfer Characteristics

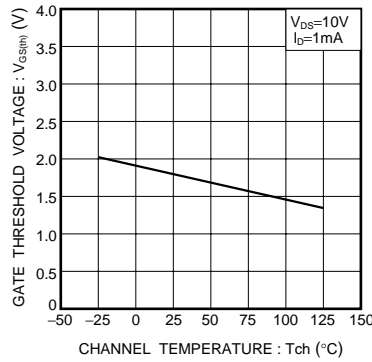


Fig.4 Gate Threshold Voltage vs. Channel Temperature

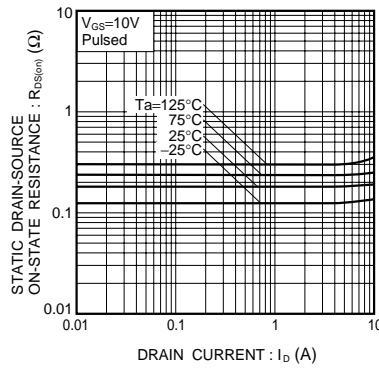


Fig.5 Static Drain-Source On-State Resistance vs. Drain Current (I)

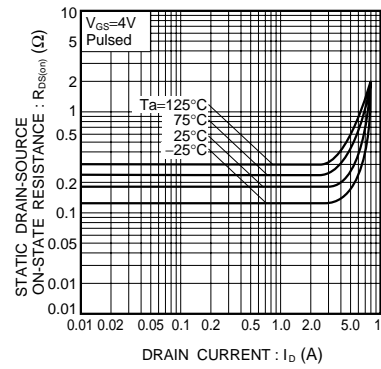


Fig.6 Static Drain-Source On-State Resistance vs. Drain Current (II)

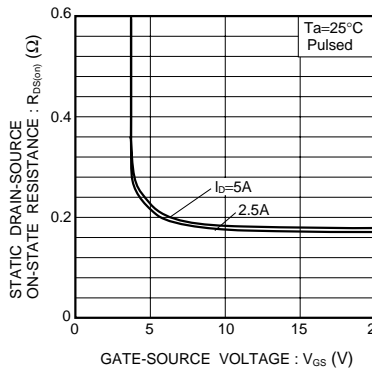


Fig.7 Static Drain-Source On-State Resistance vs. Gate-Source Voltage

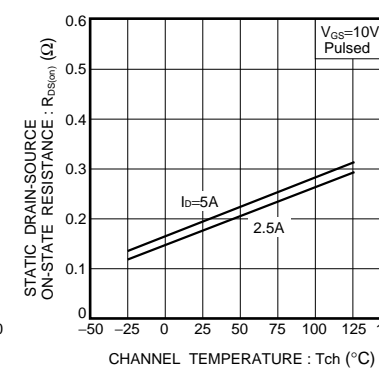


Fig.8 Static Drain-Source On-State Resistance vs. Channel Temperature

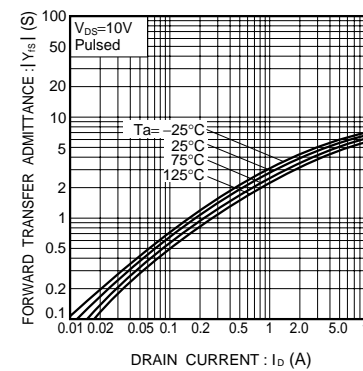


Fig.9 Forward Transfer Admittance vs. Drain Current

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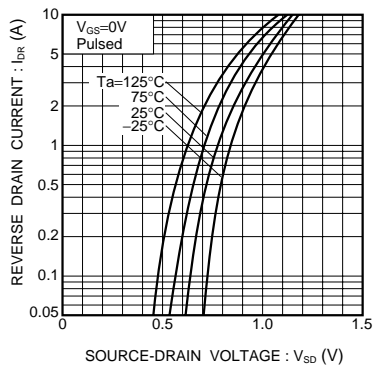


Fig.10 Reverse Drain Current vs. Source-Drain Voltage (I)

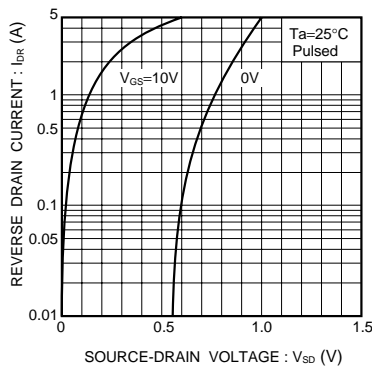


Fig.11 Reverse Drain Current vs. Source-Drain Voltage (II)

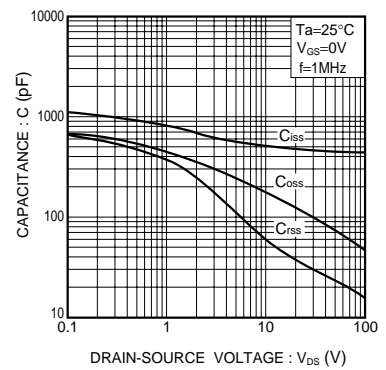


Fig.12 Typical Capacitance vs. Drain-Source Voltage

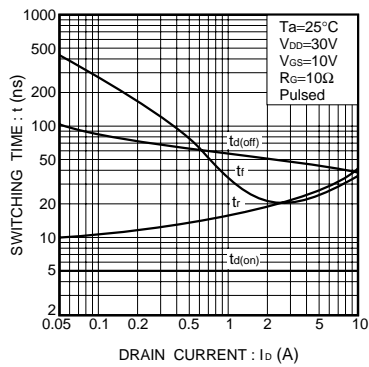


Fig.13 Switching characteristics (See Figures 16 and 17 for the measurement circuit and resultant waveforms)

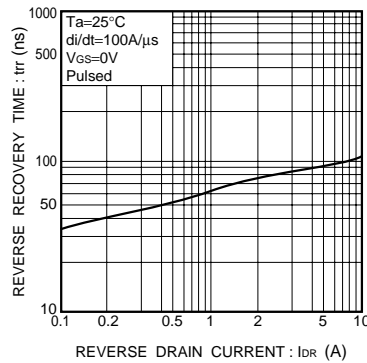


Fig.14 Reverse Recovery Time vs. Reverse Drain Current

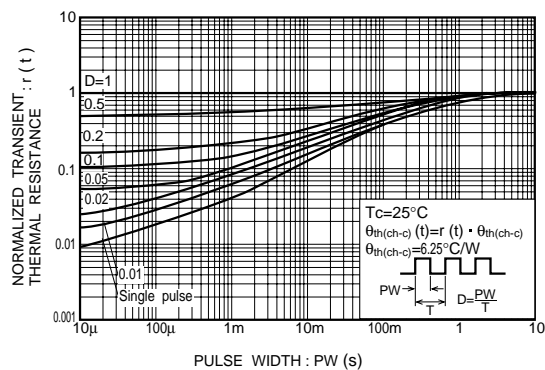


Fig.15 Normalized Transient Thermal Resistance vs. Pulse Width

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● Switching characteristics measurement circuit

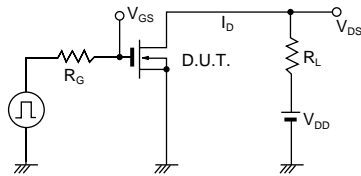


Fig.16 Switching Time Test Circuit

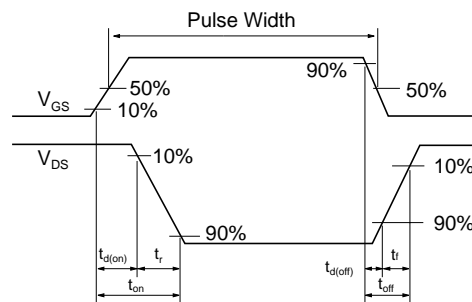


Fig.17 Switching Time Waveforms

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